SCBS071A - AUGUST 1990 - REVISED NOVEMBER 1993

- State-of-the-Art BiCMOS Design Significantly Reduces I_{CCZ}
- ESD Protection Exceeds 2000 V Per MIL-STD-883C, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)
- Full Parallel Access for Loading
- Package Options Include Plastic Small-Outline (DW) Packages, Ceramic Chip Carriers (FK) and Flatpacks (W), and Plastic and Ceramic 300-mil DIPs (J, N)

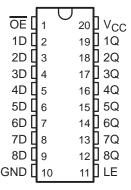
description

These 8-bit latches feature 3-state outputs designed specifically for driving highly capacitive or relatively low-impedance loads. They are particularly suitable for implementing buffer registers, I/O ports, bidirectional bus drivers, and working registers.

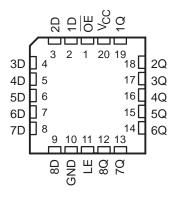
The eight latches of the 'BCT573 are transparent D-type latches. While the latch-enable (LE) input is high, the Q outputs will follow the data (D) inputs. When the latch enable is taken low, the Q outputs will be latched at the logic levels that were set up at the D inputs.

A buffered output-enable (\overline{OE}) input can be used to place the eight outputs in either a normal logic state (high or low logic levels) or a high-impedance state. In the high-impedance

SN54BCT573 ... J OR W PACKAGE SN74BCT573 ... DW OR N PACKAGE (TOP VIEW)



SN54BCT573 . . . FK PACKAGE (TOP VIEW)



state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and increased drive provide the capability to drive bus lines without need for interface or pullup components.

The output enable (\overline{OE}) does not affect the internal operations of the latches. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

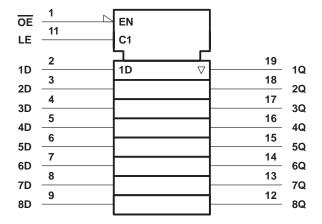
The SN54BCT573 is characterized for operation over the full military temperature range of -55° C to 125° C. The SN74BCT573 is characterized for operation from 0° C to 70° C.

FUNCTION TABLE (each latch)

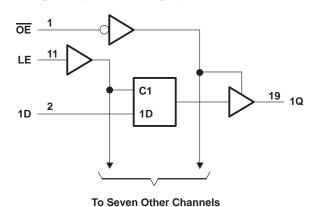
	INPUTS	OUTPUT	
OE	LE	D	Q
L	Н	Н	Н
L	Н	L	L
L	L	X	Q ₀
Н	X	Χ	Z



logic symbol†



logic diagram (positive logic)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)‡

	– 0.5 V to 7 V
	– 0.5 V to 7 V
disabled or power-off state, VO	– 0.5 V to 5.5 V
nigh state, V _O	– 0.5 V to V _{CC}
	–30 mÅ
SN54BCT573	96 mA
SN74BCT573	128 mA
SN54BCT573	– 55°C to 125°C
SN74BCT573	0°C to 70°C
	– 65°C to 150°C
	disabled or power-off state, V _O high s

[‡] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

recommended operating conditions

		SN54BCT573			SN	UNIT		
		MIN	NOM	MAX	MIN	NOM	MAX	UNII
VCC	Supply voltage	4.5	5	5.5	4.5	5	5.5	V
VIH	High-level input voltage	2			2			V
V_{IL}	Low-level input voltage			0.8			0.8	V
liK	Input clamp current			-18			-18	mA
ІОН	High-level output current	-12 -15		mA				
lOL	Low-level output current	48 64		mA				
TA	Operating free-air temperature	-55 125 0 70		°C				

[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

NOTE 1: The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TE	CT CONDITIONS	SN	SN54BCT573			SN74BCT573		
PARAWETER	15	ST CONDITIONS	MIN	TYP	MAX	MIN	TYP	MAX	UNIT
VIK	V _{CC} = 4.5 V,	I _I = -18 mA			-1.2			-1.2	V
		$I_{OH} = -3 \text{ mA}$	2.4	3.3		2.4	3.3		
Voн	V _{CC} = 4.5 V	$I_{OH} = -12 \text{ mA}$	2	3.2					V
		$I_{OH} = -15 \text{ mA}$				2	3.1		
Va	\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\	I _{OL} = 48 mA		0.38	0.55				V
VOL	V _{CC} = 4.5 V	$I_{OL} = 64 \text{ mA}$					0.42	0.55	٧
lį	V _{CC} = 5.5 V,	V _I = 5.5 V			0.4			0.4	mA
lН	V _{CC} = 5.5 V,	$V_{I} = 2.7 \text{ V}$			20			20	μΑ
Ι _{ΙL}	$V_{CC} = 5.5 \text{ V},$	$V_{I} = 0.5 V$			-0.6			-0.6	mA
los [‡]	$V_{CC} = 5.5 \text{ V},$	V _O = 0	-100		-225	-100		-225	mA
lozh	V _{CC} = 5.5 V,	V _O = 2.7 V			50			50	μΑ
lozL	V _{CC} = 5.5 V,	V _O = 0.5 V			-50			-50	μΑ
ICCL	V _{CC} = 5.5 V,	Outputs open			62			62	mA
ICCH	V _{CC} = 5.5 V,	Outputs open			8			8	mA
I _{CCZ}	V _{CC} = 5.5 V,	Outputs open			8			8	mA
C _i	V _{CC} = 5 V,	$V_{I} = 2.5 \text{ V or } 0.5 \text{ V}$		5.5			5.5		pF
Co	V _{CC} = 5 V,	V _O = 2.5 V or 0.5 V		7.5			7.5		pF

[†] All typical values are at $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

timing requirements over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

		V _{CC} = 5 V, T _A = 25°C		SN54BCT573		SN74BCT573		UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	
t _W	Pulse duration, LE high	4		4		4		ns
t _{su}	Setup time, data before LE↓	1		2.5		1		ns
th	Hold time, data after LE↓	4		4		4		ns

switching characteristics over recommended ranges of supply voltage and operating free-air temperature, $C_L = 50$ pF (unless otherwise noted) (see Note 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)		CC = 5 V 4 = 25°C		SN54B	CT573	SN74B	CT573	UNIT
	(INFOT)	(0011-01)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	
^t PLH	D	Q	2	5	7.2	1	9.8	2	8.4	ns
^t PHL		ζ	2.8	5.9	8.2	1.5	10.3	2.8	9.6	115
^t PLH	LE	Q	2.4	6.1	7.2	2	9.7	2.4	8.1	ns
^t PHL		α	2.9	5.2	7.1	2	8.8	2.9	7.8	115
^t PZH	ŌĒ	Q	3	6.2	8.5	2.5	11	3	10.4	ns
^t PZL	OE	ζ	4.3	7.1	9.3	3.5	11.5	4.3	11	115
^t PHZ	ŌĒ	Q	2.2	3.9	5.6	1.5	7.2	2.2	6	ns
t _{PLZ}		γ	1.7	3.6	5.2	1	7	1.7	6	115

NOTE 2: Load circuits and voltage waveforms are shown in Section 1.



[‡] Not more than one output should be tested at a time, and the duration of the test should not exceed one second.

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